

Glass Passivated High Efficient Rectifier

DO-41/A-405			Features								
		 Gla Hig Me LF So Co 	maxi Ider c mpor d WE	assiva ward SL lev mum dip 26 nent in EE 2	ated o surge /el 1, peak 0 °C n acc 002/9	e cap per J of 29 / 40S ordar 06/WC	-STD 50 °C nce to	-020 ROF		02/95/	PB
Primary characteristics			Applications								
I _{F(AV)}	1A	Ideal	for ac	c-to-d	c brid	lge fu	ll wav	/e rec	tifica	tion su	ck as
V _{RRM}	50V to 1000V	SMP	S, hor	me ap	plian	es, o	ffice e	equip	ment,	indus	rial
I _{FSM}	30A	autor	natior	n appl	icatio	S					
I _{RM}	5uA										
V _{FM} at I _F =1A	1.0/1.3/1.7V	Mechanical data									
$T_{\rm J}$ max.	150 °C	• DO-41/A-405									
Maximum rating (T	a=25°C unless othe	 Po Mo Re 	comr	: As m g Tor nende	narke que:1 ed To	d. 0cm-	kg(8. 5.7 ci	m-kg(os)max hes-lb	
Parameter		Sym	HER	HER			HER	HER			
									HER	HER	Unit
			101G	102G	103G	104G	105G	106G	HER 107G	HER 108G	Unit
Max. repetitive peak revers	e voltage	V _{RRM}	101G 50	102G 100	200	300	400	106G 600	107G 800	108G 1000	V
Max. RMS reverse voltage	e voltage	V _{RRM} V _{RMS}	101G 50 35	102G 100 70	200 140	300 210	400 280	106G 600 420	107G 800 560	108G 1000 700	V V
Max. RMS reverse voltage Max. DC blocking voltage		VRRM VRMS VDC	101G 50	102G 100	200	300 210 300	400 280 400	106G 600	107G 800	108G 1000	V V V
Max. RMS reverse voltage Max. DC blocking voltage Max. average forward curre	ent	V _{RRM} V _{RMS}	101G 50 35	102G 100 70	200 140	300 210 300	400 280	106G 600 420	107G 800 560	108G 1000 700	V V
Max. RMS reverse voltage Max. DC blocking voltage	ent d surge current	VRRM VRMS VDC	101G 50 35	102G 100 70	200 140	300 210 300	400 280 400	106G 600 420	107G 800 560	108G 1000 700	V V V
Max. RMS reverse voltage Max. DC blocking voltage Max. average forward curre Non-repetitive peak forward	ent d surge current e	VRRM VRMS VDC IF(AV)	101G 50 35	102G 100 70 100	200 140	300 210 300	400 280 400 1	106G 600 420	107G 800 560	108G 1000 700	V V V A
Max. RMS reverse voltage Max. DC blocking voltage Max. average forward curre Non-repetitive peak forware 8.3ms single half-sine-wav	ent d surge current e d voltage drop per diode	VRRM VRMS VDC IF(AV) IFSM VFM	101G 50 35	102G 100 70 100	200 140 200	300 210 300	400 280 400 1	106G 600 420	107G 800 560 800	108G 1000 700	V V A A V
Max. RMS reverse voltage Max. DC blocking voltage Max. average forward curro Non-repetitive peak forwar 8.3ms single half-sine-way Max. instantaneous forward	ent d surge current e d voltage drop per diode e current Ta=25 °C	VRRM VRMS VDC IF(AV) IFSM	101G 50 35	102G 100 70 100	200 140 200	300 210 300	400 280 400 1 30 1.3	106G 600 420	107G 800 560 800	108G 1000 700	V V V A A
Max. RMS reverse voltage Max. DC blocking voltage Max. average forward curre Non-repetitive peak forward 8.3ms single half-sine-wav Max. instantaneous forward Max. instantaneous reverse	ent d surge current e d voltage drop per diode e current Ta=25 °C ra=125 °C	VRRM VRMS VDC IF(AV) IFSM VFM	101G 50 35	102G 100 70 100	200 140 200	300 210 300 3	400 280 400 1 30 1.3 5	106G 600 420	107G 800 560 800	108G 1000 700	V V A A V V μΑ •C
Max. RMS reverse voltage Max. DC blocking voltage Max. average forward curre Non-repetitive peak forware 8.3ms single half-sine-wav Max. instantaneous forware Max. instantaneous reverse at rated DC blocking voltage Operating junction temperature	ent d surge current e d voltage drop per diode e current Ta=25 °C ge Ta=125 °C ture	VRRM VRMS VDC IF(AV) IFSM VFM IRM	101G 50 35	102G 100 70 100	200 140 200	300 210 300 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3	400 280 400 1 30 1.3 5 00	106G 600 420	107G 800 560 800	108G 1000 700	∨ ∨ A A V µA °C °C
Max. RMS reverse voltage Max. DC blocking voltage Max. average forward curre Non-repetitive peak forward 8.3ms single half-sine-wav Max. instantaneous forward Max. instantaneous reverse at rated DC blocking voltage Operating junction tempera	ent d surge current e d voltage drop per diode e current Ta=25 °C ge Ta=125 °C ture	VRRM VRMS VDC IF(AV) IFSM VFM IRM TJ	101G 50 35	102G 100 70 100	200 140 200	300 210 300 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3	400 280 400 1 30 1.3 5 00 +150	106G 600 420	107G 800 560 800	108G 1000 700	V V A A V V µA ∘C

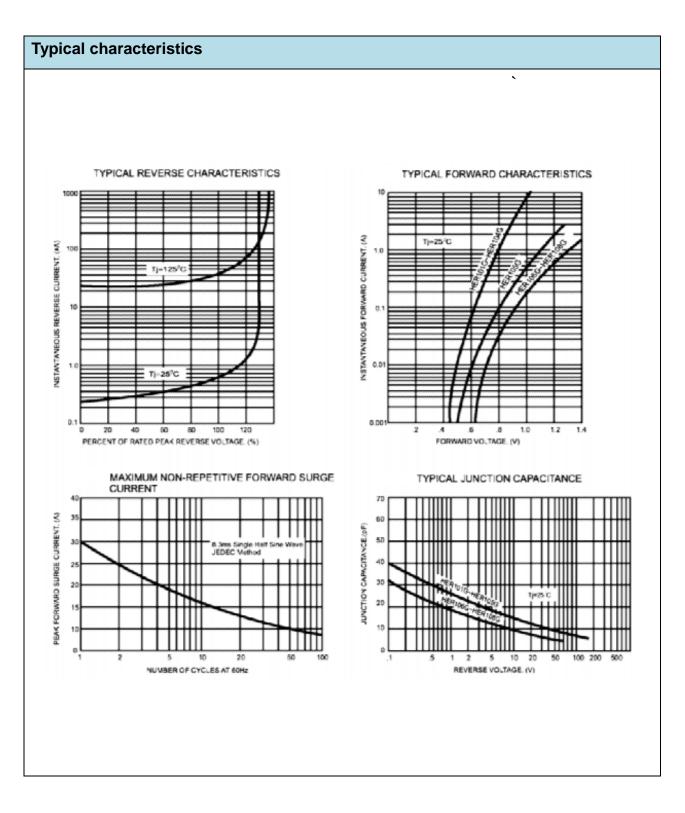
Notes:

1 Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A



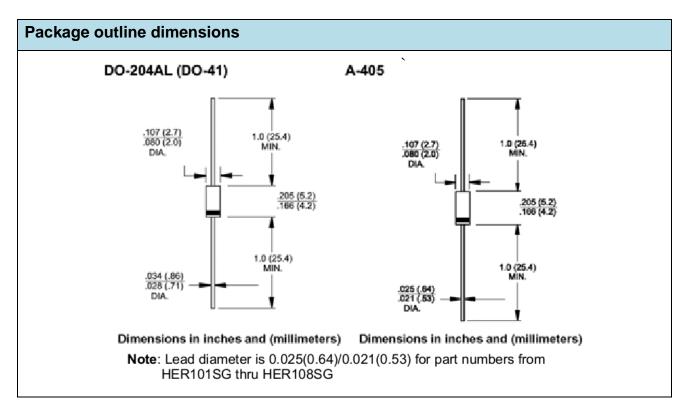
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Ordering information (Example)									
PREFERRED	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE					
HER108G									





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